

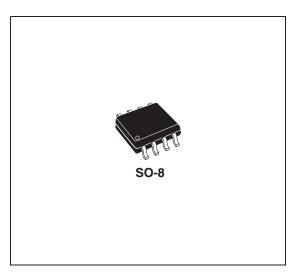
High voltage high-side driver

Features

- High voltage rail up to 450 V
- dV/dt immunity ±50 V/nsec in full temperature range
- Driver current capability: 500 mA source, 500 mA sink
- Switching times 100 ns rise/fall with 2.5 nF load
- CMOS/TTL Schmitt trigger inputs with hysteresis and pull down
- Under voltage lock out
- Clamping on V_{CC}
- Non inverting input
- Reset circuitry
- SO8 package

Description

The L9857 is an high voltage device, manufactured with the BCD "off-line" technology.



It has the capability of driving N channel PowerMOS transistors. The upper (floating) section is enabled to work with voltage rail up to 450 V. The logic inputs are CMOS/TTL compatible for ease of interfacing with controlling devices..

Table 1. Device summary

Order code	Order code Op. temp range, °C		Packing
L9857-TR	-40 to +125	SO-8	Tape and reel
L9857-TR-LF	-40 to +125	SO-8	Tape and reel

Content L9857

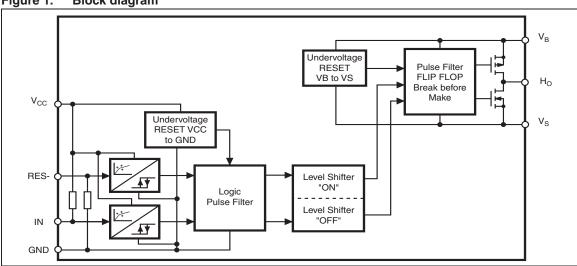
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1 Block diagram and pin description

1.1 Block diagram

Figure 1. Block diagram



1.2 Pin description

Figure 2. Pin connection (top view)

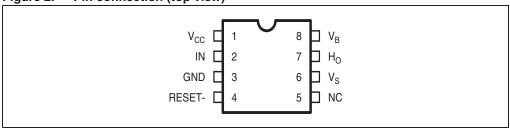


Table 2. Pin function

Pin #	Pin name	Description	
1	V_{CC}	Driver supply, typically 17V	
2	IN	Driver control signal input (positive logic)	
3	GND	Ground	
4	RESET-	Driver enable signal input (negative logic)	
5	NC	No connection (no bondwire)	
6	V _S	MOSFET source connection	
7	H _O	MOSFET gate connection	
8	V _B	Driver output stage supply	

2 Electrical specifications

2.1 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{th(j-amb)}	Thermal resistance junction-to-ambient Max.	150	°C/W

2.2 Absolute maximum ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to GND, all currents are defined positive into any lead. This is a stress only rating and operation of the device at these or any conditions exceeding those indicated in the operational sections of this specifications is not implied.

Table 4. Absolute maximum ratings

	Parameter	Va	Units		
Symbol	Definition	Min.	Max.	Units	
V _{BS}	High side floating supply voltage	-0.3	20	V	
V _B	High side driver output stage voltage	-0.3	300	V	
V _S	High side floating supply offset voltage	V _B – 20	300	V	
VH _O	Output voltage gate connection	V _S - 0.3	V _B + 0.3	V	
V _{CC}	Supply voltage	-0.3	20	V	
V _{IN}	Input voltage	-0.3	V _{CC} + 0.3	V	
I _{IN}	Input injection current. Full function, no latch-up; (guaranteed by design). Test at 10 V and 17 V on eng. samples.	-	+1	mA	
V _{RES}	Reset input voltage	-0.3	V _{CC} + 0.3	V	
V _{esd}	Electrostatic discharge voltage (human body model)	2k	-	V	
V _{CDM}	Charge device model CDM, EOS/ESD ass. std 5.3. number of discharges per pin: 6	500	-	V	
dV/dt	Allowable offset voltage slew rate	-50	50	V/nsec	
T _j	Junction temperature	-55	150		
T _{stg}	Storage temperature -55 150				
TL	Lead temperature (soldering, 10 seconds) 3 times Bosch soldering profil acc. to Bosch soldering conditions, gen. spec.	-	300	°C	

2.3 Recommended operating conditions

For proper operations the device should be used within the recommended conditions.

Table 5. Recommended operating conditions

	Parameter	Val	Units		
Symbol	Definition	Min.	Max.	Onits	
V _B	High side driver output stage voltage -5 V transient 0.1µs	VS+10 ⁽¹⁾	VS+18	V	
V _S	High side floating supply offset voltage - 20 V transient 0.1µs	-5	300	V	
V _{HO}	Output voltage gate connection	Vs	V _B	V	
V _{CC}	Supply voltage	10	18	V	
V _{IN}	Input voltage	0	V _{CC}	V	
V _{RES}	Reset input voltage	0	V _{CC}	V	
F _S	Switching frequency	-	200	kHz	
T _{amb}	Ambient temperature	-40	125	°C	

^{1.} Reset-Logic functional for V_B - V_S =2V, independent from VCC-level

2.4 Electrical characteristics

Unless otherwise specified, V_{CC} = 15 V, V_{BS} = 15 V, V_S = 0 V, IN = 0 V, RES = 5 V, load R = 50 Ω , C = 2.5 nF. Unless otherwise noted, these specifications apply for an operating junction temperature range of -40 °C \leq T $_{\rm j}$ \leq 125 °C

Table 6. Electrical characteristics

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit		
V _{CC} suppl	V _{CC} supply							
V _{CCUV}	V _{CC} supply undervoltage	V _{CC} rising from 0 V V _{CC} dropping from 10 V	7.2	-	9.6	V		
V _{CCUVHYS}	V _{CC} supply undervoltage lockout hysteresis	-	0.02	0.2	0.4	V		
td _{UVCC}	Undervoltage lockout response time	V _{CC} steps either from 10 V to 6 V or from 6 V to 10 V	0.5	-	20	μS		
I _{QCC}	V _{CC} supply current	-	-	-	400	μΑ		
V _{BS} suppl	V _{BS} supply							
V _{BSUV}	V _{BS} supply undervoltage	V _{BS} rising from 0 V V _{BS} dropping from 10 V	7.2	-	9.6	V		
td _{UVBS}	Undervoltage lockout response time	V _{BS} steps either from 10 V to 6 V or from 6 V to 10 V	0.5	-	20	μS		

Table 6. Electrical characteristics (continued)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V _{BSUVHYS}	V _{BS} supply undervoltage lockout hysteresis	-	0.02	0.2	0.4	V
I _{QBS1}	V _{BS} supply current	static mode, V _{BS} = 10 V, IN = 0 V or 5 V	-	-	100	μА
I _{QBS2}	v _{BS} supply current	static mode, V _{BS} = 18 V, IN = 0 V or V _{CC}	-	-	200	μА
ΔV _{BS}	V _{BS} drop due to output turn-on	$V_{BS} = 17 \text{ V}, C_{BS} = 1 \mu\text{F}, \\ td_{IG-IN} = 3 \mu\text{s}, t_{TEST} = 100 \mu\text{s}$	-	-	210	mV
Gate drive	er characteristics			•		
I _{PKSo1}		$V_{BS} = 10 \text{ V}$, $T_j = 25 ^{\circ}\text{C}$ $PW \leq 10 \mu\text{s}$	120	250	-	
I _{PKSo2}	Dock cuttout course outwork	$V_{BS} = 10 \text{ V}$ PW $\leq 10 \mu\text{s}$	70	150	-	A
I _{PKSo3}	Peak output source current	V_{BS} = 17 V, T_j = 25 °C PW \leq 10 μs	250	500	-	mA
I _{PKSo4}		$V_{BS} = 17 \text{ V},$ $PW \le 10 \mu\text{s}$	150	300	-	
I _{HOH,off}	HOH off-state leakage current	Guaranteed by design	-	-	1	μА
t _{r1}		$V_{BS} = 10 \text{ V}, T_j = 25^{\circ}\text{C}$	-	0.2	0.4	μs
t _{r2}	Output rise time	V _{BS} = 10 V	-	0.3	0.5	
t _{r3}	Output rise time	$V_{BS} = 17 \text{ V}, T_j = 25 ^{\circ}\text{C}$	-	0.1	0.2	
t _{r4}		V _{BS} = 17 V	-	0.15	0.3	
I _{PKSi1}		$\begin{split} &\text{IN} = \text{V}_{\text{CC}}, \text{T}_{j} = 25 ^{\circ}\text{C} \\ &\text{V}_{\text{BS}} = 10 \text{V}, \text{PW} < 10 \mu\text{s} \end{split}$	120	250	-	
I _{PKSi2}	Dools outrout oints ourroant	$\begin{split} &IN = V_{CC}, \\ &V_{BS} = 10V \;, \; PW < 10 \; \mu s \end{split}$	70	150	-	A
I _{PKSi3}	Peak output sink current	$IN = V_{CC}, T_j = 25 ^{\circ}C$ $V_{BS} = 17 V, PW < 10 \mu s$	250	500	-	mA
I _{PKSi4}		$\begin{split} &\text{IN} = \text{V}_{\text{CC}}, \\ &\text{V}_{\text{BS}} = 17 \text{ V, PW} < 10 \mu\text{s} \end{split}$	150	300	-	
t _{f1}		$V_{BS} = 10 \text{ V}, T_j = 25 ^{\circ}\text{C}$	-	0.2	0.4	
t _{f2}	Output fall time	V _{BS} = 10 V	-	0.3	0.5	
t _{f3}	Output fall time	$V_{BS} = 17 \text{ V, } T_j = 25 ^{\circ}\text{C}$	-	0.1	0.2	μS
t _{f4}		V _{BS} = 17 V	-	0.15	0.3	
t _{plh}	Input-to-output turn-on propogation delay (50 % input level to 10 % output level)	-	-	0.1	0.3	μs

Table 6. Electrical characteristics (continued)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit	
t _{phl}	Input-to-output turn-off propagation delay (50 % input level to 90% output level)	-	-	0.1	0.2		
tphl_res	RES-to-output turn-off propogation delay (50% input level to 90% output levels)	-	-	0.1	0.3	μs	
tplh_res	RES-to-output turn-on propogation delay (50% input level to 10% output levels)	-	-	0.1	0.8		
Input cha	Input characteristics						
V _{INH}	High logic level input threshold	-	9.5	-	-	V	
V _{INL}	Low logic level input threshold	-	-	-	6	V	
R _{IN}	High logic level input resistance (Pull-down resistor)	-	60	-	300	kΩ	
I _{IN}	Low logic level input current	V _{IN} = 0	-	-	5	μА	
V _{H_RES}	High logic level RES input threshold	Reset signal comes from a 5 V system!	3.5	-	-	V	
V _{L_RES}	Low Logic Level RES input threshold	R eset signal comes from a 5V system!	-	-	1.4	V	
R _{RES}	High logic level RES input resistance (Pull-down resistor)	Reset signal comes from a 5 V system with pull-up resistor 3.8 k Ω to 5 V. $^{(1)}$	60	-	300	kΩ	
I _{RES}	Low logic level input current	V _{RES} = 0	-	-	5	μА	

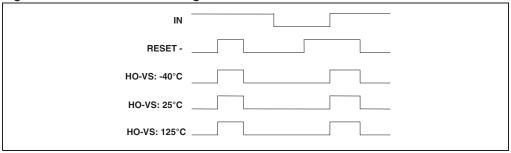
^{1. 4} HS-driver reset- inputs and other IC with their input pull-down resistors are connected in parallel with the RESET wire.

The enable input RES- is an active low input, that means a logic low turns the external Power MOSFET off. The input circuitry has to make sure, that the MOSFET is off, when the pin is open or floating. In the application the RES- pin is tied to a bipolar open collector transistor or MOSFET open drain transistor with pull-up resistor 3.8K to +5V together with other RES- inputs of other IC.

2.5 Reset functional diagram

The diagram is guaranteed for the following condition. V_{CC} = 10 V; V_{BS} = 10 V @ -40 °C, V_{CC} = 17 V; V_{BS} = 17 V @ +25 °C and 125 °C

Figure 3. Reset functional diagram



Timing diagrams L9857

3 Timing diagrams

Figure 4. Input/output timing diagram

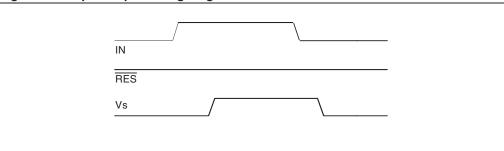
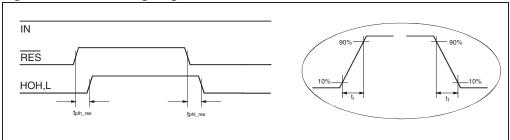


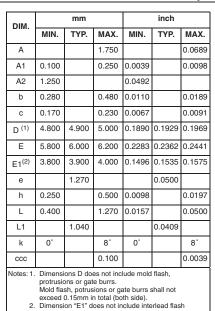
Figure 5. Reset timing diagram



4 Package information

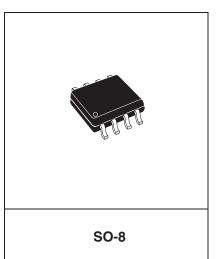
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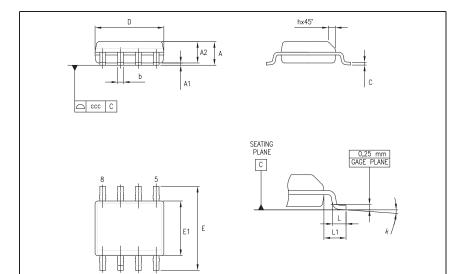
Figure 6. SO-8 mechanical data and package dimensions



or protrusions. Interlead flash or protrusions shall not exceed 0.25mm per side.

OUTLINE AND MECHANICAL DATA





0016023 D

Revision history L9857

5 Revision history

Table 7. Document revision history

Date	Revision	Changes	
20-Nov-2006	1	Initial release.	
07-Oct-2009	2	Updated Table 1: Device summary.	
17-Sept-2013	3	Updated Disclaimer	

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